

[This question paper contains 4 printed pages.]

Sr. No. of Question Paper : 1572

F-3

Your Roll No.....

Unique Paper Code : 2511303

Name of the Course : B.Tech Electronics

Name of the Paper : Analog Electronics – I

Semester : III

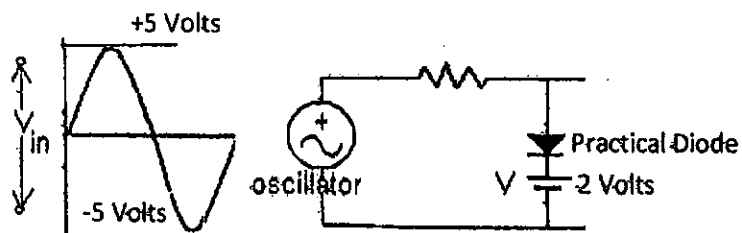
Duration : 3 Hours

Maximum Marks : 75

Instructions for Candidates

1. Write your Roll No. on the top immediately on receipt of this question paper.
2. Attempt FIVE questions in all.
3. Question No. 1 is compulsory.
4. Use of Scientific Calculator is allowed.

1. (a) Sketch the output of the given circuit with suitable explanation if a practical silicon diode is used. (3)

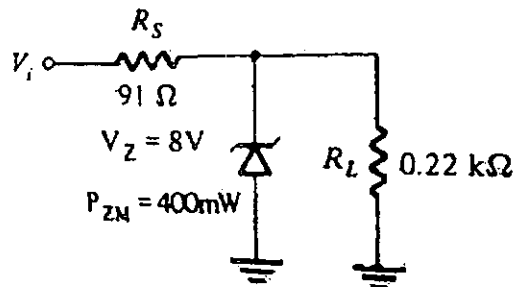


- (b) Explain the meaning of static and dynamic resistances of the diode. (3)
- (c) Draw and explain the Output Characteristics of Common Emitter (CE) transistor (n-p-n type). (3)

P.T.O.

- (d) A three section RC phase shift oscillator has $R = 10\text{K}\Omega$ and $C = 0.001\mu\text{f}$. What is the frequency of oscillation ? If the oscillator is to be made variable, using same value of R , what should be the tuning range of capacitor for frequency range of 1 to 100 kHz ? (3)
- (e) Differentiate between voltage and power amplifier. (3)
2. (a) What are Clampers ? Give one application. Draw and explain the circuit of biased positive clamper. (6)
- (b) Analyze Zener diode voltage regulator for
- (i) V_i and R_L Fixed
 - (ii) Fixed V_i , Variable R_L
 - (iii) Fixed R_L , Variable V_i (6)
- (c) What is the ripple factor of a Full Wave Rectifier (FWR) with capacitor filter if the value of $R_L = 1\text{K}\Omega$ and $C = 10\mu\text{F}$. (3)
3. (a) Derive the expressions for Current gain, Voltage gain, input resistance and output resistance of CE amplifier using H-parameters. (8)
- (b) Find the operating point and draw the load line of a voltage divider self bias circuit using n-p-n transistor biased in active region. Given $\beta = 100$, $V_{CC} = 12\text{ V}$, $R_1 = 60\text{ K}\Omega$, $R_2 = 10\text{ K}\Omega$, $R_C = 5\text{ K}\Omega$ and $R_E = 1\text{ K}\Omega$. (5)
- (c) Explain the concept of thermal runaway. (2)
4. (a) Distinguish between positive and negative feedback. Give one application of each. (4)

- (b) Derive the expression of Input Resistance, Current Gain, Voltage Gain and Output Resistance for Voltage Series Feedback circuit. (8)
- (c) A voltage amplifier with a gain of 50dB employ's $1/50^{\text{th}}$ of its output to negative feedback. Calculate gain with feedback. (3)
5. (a) Prove that efficiency of Class B power amplifier is 78%. (6)
- (b) Calculate Power efficiency of Class A transformer coupled amplifier if $V_{CC} = 15 \text{ V}$ and $R_L = 15\Omega$. (3)
- (c) Derive the expression of voltage gain for a common source JFET amplifier using small signal model. (6)
6. (a) Draw the circuits for Centre-tap Full Wave rectifier and Bridge rectifier and derive the expression for efficiency for the same.
- (b) Determine the range of V_i that will maintain output voltage (V_L) at 8 V and not exceed the maximum power rating of the zener diode. (3)



- (c) Assume that a n-p-n Si-transistor based Voltage divider circuit with $\beta = 50$, $V_{BE} = 0.6\text{V}$, $V_{CC} = 22.5\text{V}$ and $R_C = 5.6\text{K}\Omega$, it is desired to establish a Q-point at $V_{CE} = 12\text{V}$, $I_C = 1.5 \text{ mA}$ and a stability factor $S \leq 3$. Find R_1 , R_2 and R_E . (6)

7. (a) Draw the circuit diagram of Colpitt Oscillator (transistor based) circuit and derive the expression of the frequency of oscillation for the same. (8)
- (b) Explain how even harmonics are eliminated in push pull amplifier configuration. (3)
- (c) For transformer coupled Class A amplifier, the transformer has a turn ratio of 10:1 and secondary load resistance is 10Ω . If the zero signal collector current is 100 mA, find the output power. (4)